International Rectifier ISR

2KBB SERIES 1.9A single phase rectifier bridge

Maximum Ratings and Characteristics

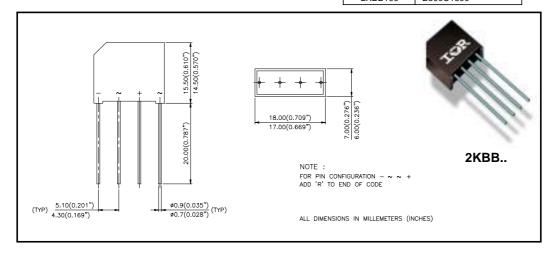
		2KBB	Units	
I _o		1.9	Α	
I _{FSM}	50Hz	50	Α	
	60Hz	52	Α	
l²t	50Hz	17.7	A²s	
	60Hz	16.1	A²s	
V_{RRM}		100 to 1000	V	
T _J		-40 to 150	°C	

Description/Features

A 1.9A single phase diode brodge rectifier assembly consisting of four silicon junction diodes in a plastic encapsulation, intended for general applications in industrial and consumer equipment.

- Suitable for printed circuit board mounting
- Leads on standard 2.54mm (0.1in.) grid
- Compact construction
- High surge current capability
- Polarized package
- Equivalent to standard DIN parts

Part number	DIN code equivalent		
2KBB05	B20C1500		
2KBB10	B40C1500		
2KBB20	B80C1500		
2KBB40	B125C1500		
2KBB60	B250C1500		
2KBB80	B380C1500		
2KBB100	B500C1500		





Reverse voltage ratings and application data

	V _{RRM} , V _{RSM}	I _{RM} , typical peak		Application data (see figure 3)			
Part number	max. peak	rev. current per diode		V _{RSM} max.	C _{max} max.	R _{min} min.	
	rev. voltage	at rated V _{RRM}		recommended AC	load	source	
	$T_J = 15^{\circ}C$	$T_J = 150^{\circ}C$		supply voltage	capacitance	resistance	
	V	μΑ	μA	V	μF	Ω	
2KBB05, 2KBB05R	50	10	500	20	7000	0.3	
2KBB10, 2KBB10R	100	10	500	40	5000	0.5	
2KBB20, 2KBB20R	200	10	500	80	3300	0.8	
2KBB40, 2KBB40R	400	10	500	125	1600	1.5	
2KBB60, 2KBB60R	600	10	500	250	1200	2.5	
2KBB80, 2KBB80R	800	10	500	380	800	3.0	
2KBB100, 2KBB100R	1000	10	500	500	600	5.0	

Electrical Specification Forward Conduction

	Parameters	2KBB	Unit	Conditions	
Io	Maximum DC output current	1.9	А	T _C =45°C, Resistive & inductive load	
		1.5		T _C =45°C, Capacitive load	
I _{FSM}	Maximum peak, one-cycle non-repetitive surge current,	50		t = 6ms Following any rated load condition, and with rated	
		52		t = 5ms V _{RRM} applied following surge	
I ² t	Maximum I ² t for fusing,	12.5	A ² s	t = 10ms RatedV _{RRM} appliedfollowing	
	initial $T_J = T_J max$	11.3		$t = 8.3 \text{ms}$ surge, initial $T_J = 150 ^{\circ}\text{C}$	
		17.7	A ² s	t = 10ms	
		16.1		t = 8.3ms	
I ² √t	Maximum I ² √t capability	177	A ² √s	V _{RRM} following surge = 0, t = 0.1 to 10 ms	
	forfusing			I^2 t for time $t_x = I2\sqrt{t} \cdot \sqrt{t_x}$	
V _{FM}	Maximum peak forward voltage per diode	1.1	V	$I_0 = 1.9A (3.0 A pk)$	
f	Operatingfrequencyrange	40 to 2000	Hz		

Thermal and Mechanical Specifications

	Parameters	2KBB	Unit	Conditions
T _J	Operating and storage temperature range	-40 to 150	°C	
Wt	Approximate weight	4 (0.14)	g(oz)	

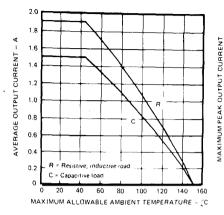


Fig. 1 — Average (DC) Output Current Vs. Maximum
Allowable Ambient Temperature

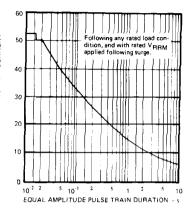


Fig. 2 — Maximum Non-repetitive Surge Current Vs. Pulse Train Duration (f = 50 Hz)

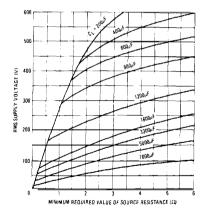


Fig. 3 — Minimum Required Source Resistance Vs. RMS Supply Voltage and Load Capacitance

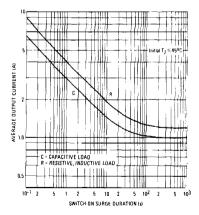


Fig. 4 — Maximum Switch-On Surge Current Vs. Surge Duration